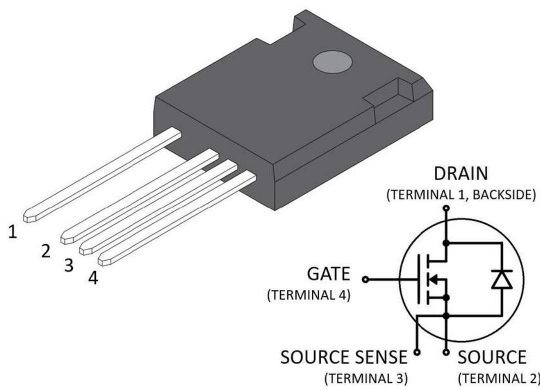
MSC080SMA330B4

3300 V, 80 mΩ SiC N-Channel Power MOSFET

Product Overview

The silicon carbide (SiC) power MOSFET product line from Microchip increases the performance over silicon MOSFET and silicon IGBT solutions while lowering the total cost of ownership for high-voltage applications. The MSC080SMA330B4 device is a 3300 V, 80 mΩ SiC MOSFET in a TO-247 4-lead package with a source sense.



Features

The following are key features of the MSC080SMA330B4 device:

- Low capacitances and low gate charge
- Fast switching speed due to low internal gate resistance (ESR)
- Stable operation at high junction temperature, $T_{J(max)}$ = 150 °C
- Fast and reliable body diode
- Superior avalanche ruggedness
- RoHS compliant

Benefits

The following are benefits of the MSC080SMA330B4 device:

- High efficiency to enable lighter, more compact system
- Simple to drive and easy to parallel
- Improved thermal capabilities and lower switching losses
- Eliminates the need for external freewheeling diode
- Lower system cost of ownership

Applications

The MSC080SMA330B4 device is designed for the following applications:

- PV inverter, converter, and industrial motor drives
- Smart grid transmission and distribution
- Induction heating and welding
- H/EV powertrain and EV charger
- Power supply and distribution

1. Device Specifications

This section shows the specifications of the MSC080SMA330B4 device.

1.1 Absolute Maximum Ratings

The following table shows the absolute maximum ratings of the MSC080SMA330B4 device.

Table 1-1. Absolute Maximum Ratings

Symbol	Parameter	Ratings	Unit
V_{DSS}	Drain source voltage	3300	V
I_D	Continuous drain current at T_C = 25 °C	41	A
	Continuous drain current at T_C = 100 °C	26	
I_{DM}	Pulsed drain current[1]	100	
V_{GS}	Gate-source voltage	23 to –10	V
P_D	Total power dissipation at T_C = 25 °C	381	W
	Linear derating factor	3.04	W/°C

Note:

1. Repetitive rating: pulse width and case temperature limited by maximum junction temperature.

The following table shows the thermal and mechanical characteristics of the MSC080SMA330B4 device.

Table 1-2. Thermal and Mechanical Characteristics

Symbol	Characteristic/Test Conditions	Min	Typ	Max	Unit
$R_{\theta JC}$	Junction-to-case thermal resistance		0.22	0.33	°C/W
T_J	Operating junction temperature	–55		150	°C
T_{STG}	Storage temperature	–55		150	°C
T_L	Soldering temperature for 10 seconds (1.6 mm from case)			300	°C
	Mounting torque, 6-32 or M3 screw			10	lbf-in
				1.1	N-m
Wt	Package weight		0.22		oz
			6.2		g

1.2 Electrical Performance

The following table shows the static characteristics of the MSC080SMA330B4 device. T_J = 25 °C unless otherwise specified.

Table 1-3. Static Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$V_{(BR)DSS}$	Drain-source breakdown voltage	V_{GS} = 0 V, I_D = 100 µA	3300			V
$R_{DS(on)}$	Drain-source on resistance[1]	V_{GS} = 20 V, I_D = 30 A		84	105	mΩ

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Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$V_{GS(th)}$	Gate-source threshold voltage	$V_{GS} = V_{DS}$, I_D = 3 mA	1.9	2.97		V
I_{DSS}	Zero gate voltage drain current	V_{DS} = 1200 V, V_{GS} = 0 V			100	μA
		V_{DS} = 1200 V, V_{GS} = 0 V, T_J = 125 °C			500	
I_{GSS}	Gate-source leakage current	V_{GS} = 20 V/–10 V			±100	nA

Note:

1. Pulse test: pulse width < 380 μs, duty cycle < 2%.

The following table shows the dynamic characteristics of the MSC080SMA330B4 device. T_J = 25 °C unless otherwise specified.

Table 1-4. Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
C_{iss}	Input capacitance	V_{GS} = 0 V V_{DD} = 2400 V V_{AC} = 25 mV f = 200 kHz		3462		pF
C_{rss}	Reverse transfer capacitance			4		
C_{oss}	Output capacitance			77		
Q_g	Total gate charge	V_{GS} = –5 V/20 V V_{DD} = 2650 V I_D = 30 A		55		nC
Q_{gs}	Gate-source charge			51		
Q_{gd}	Gate-drain charge			161		
$t_{d(on)}$	Turn-on delay time	V_{DD} = 2310 V V_{GS} = –5 V/20 V I_D = 20 A $R_{g(ext)}$ = 8 Ω Freewheeling diode = MSC080SMA330B4 (V_{GS} = –5 V) (reference Fig. 1-20)		34		ns
t_r	Voltage rise time			25		
$t_{d(off)}$	Turn-off delay time			50		
t_f	Voltage fall time			32		
E_{on}	Turn-on switching energy			1590		μJ
E_{off}	Turn-off switching energy			450		
$t_{d(on)}$	Turn-on delay time	V_{DD} = 2310 V V_{GS} = –5 V/20 V I_D = 20 A $R_{g(ext)}$ = 8 Ω Freewheeling diode = MSC030SDA330B (reference Fig. 1-20)		35		ns
t_r	Voltage rise time			18		
$t_{d(off)}$	Turn-off delay time			50		
t_f	Voltage fall time			22		
E_{on}	Turn-on switching energy			1300		μJ
E_{off}	Turn-off switching energy			360		
ESR	Gate equivalent series resistance	f = 1 MHz, 25 mV, drain short		3.7		Ω
E_{AS}	Avalanche energy, single pulse	V_{DS} = 150 V, I_D = 30 A		100		mJ

The following table shows the body diode characteristics of the MSC080SMA330B4 device. T_J = 25 °C unless otherwise specified.

Table 1-5. Body Diode Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
V_{SD}	Diode forward voltage	I_{SD} = 30 A, V_{GS} = 0 V		4.0		V
		I_{SD} = 30 A, V_{GS} = –5 V		4.2		
t_{rr}	Reverse recovery time	I_{SD} = 20 A, V_{GS} = –5 V, Drive Rg = 8 Ω, V_{DD} = 2310 V, dI/dt = –3760 A/µs		35		ns
Q_{rr}	Reverse recovery charge			818		nC
I_{RRM}	Reverse recovery current			41		A

1.3 Typical Performance Curves

This section shows the typical performance curves of the MSC080SMA330B4 device.

Figure 1-1. Drain Current vs. V_{DS} at T_J

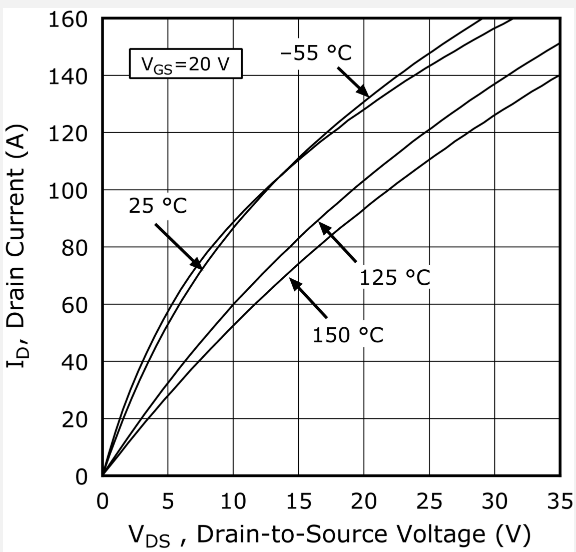


Figure 1-2. Drain Current vs. V_{DS} at V_{GS}

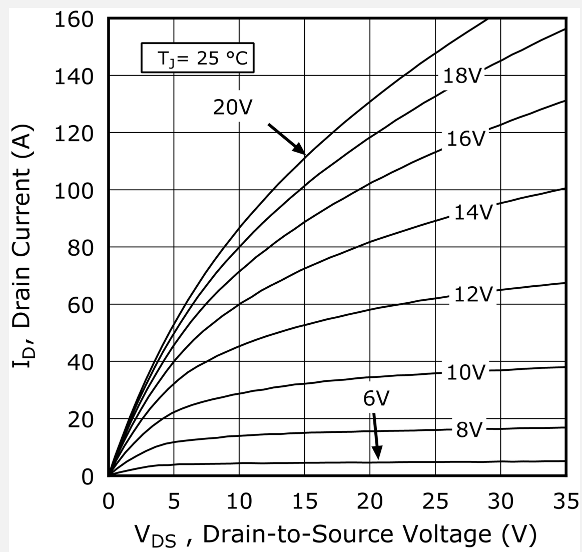


Figure 1-3. Drain Current vs. V_{DS} at V_{GS}

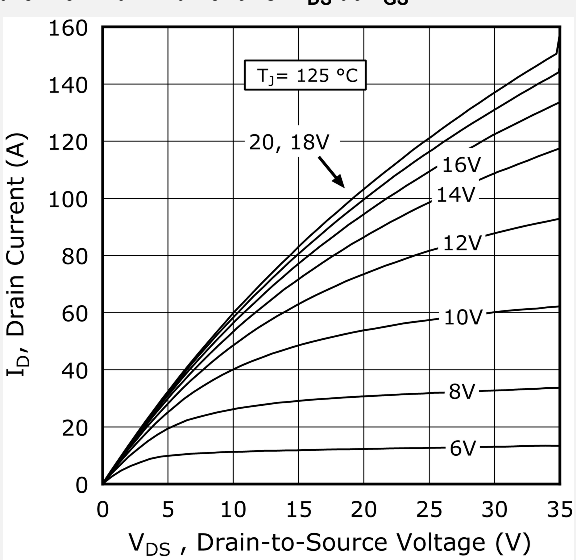


Figure 1-4. Drain Current vs. V_{DS} at V_{GS}

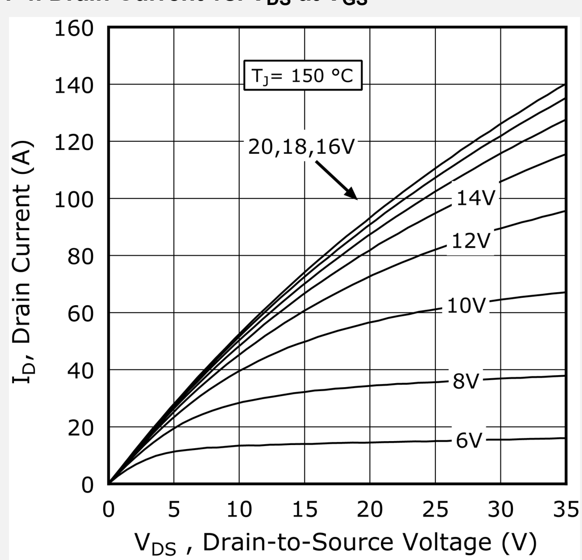


Figure 1-5. $R_{DS(on)}$ vs. Junction Temperature

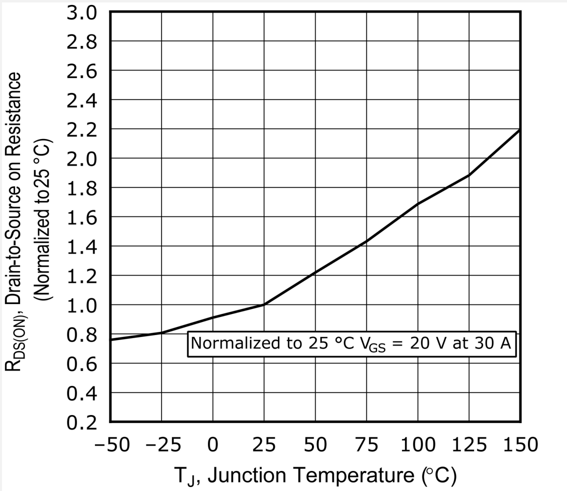


Figure 1-6. Gate Charge Characteristics

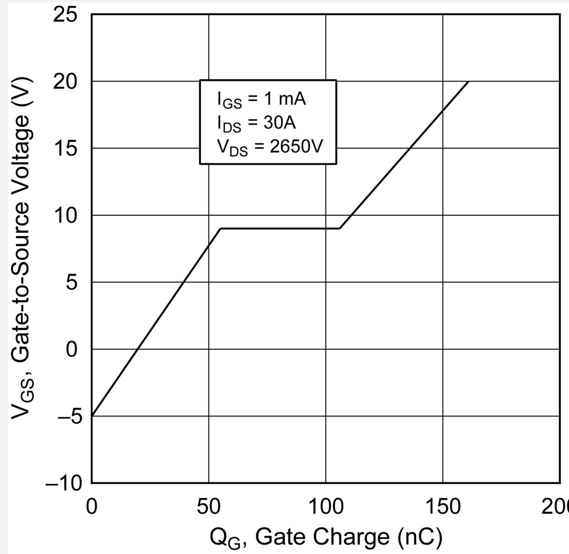


Figure 1-7. Capacitance vs. Drain-to-Source Voltage

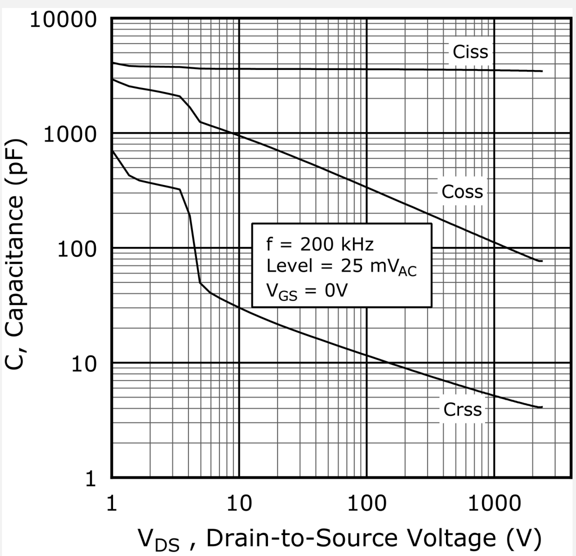


Figure 1-8. I_D vs. V_{DS} 3[rd] Quadrant Conduction

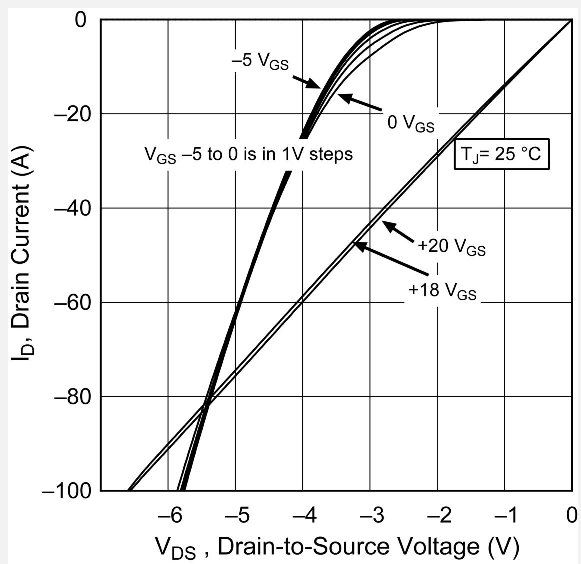


Figure 1-9. I_D vs. V_{DS} 3rd Quadrant Conduction

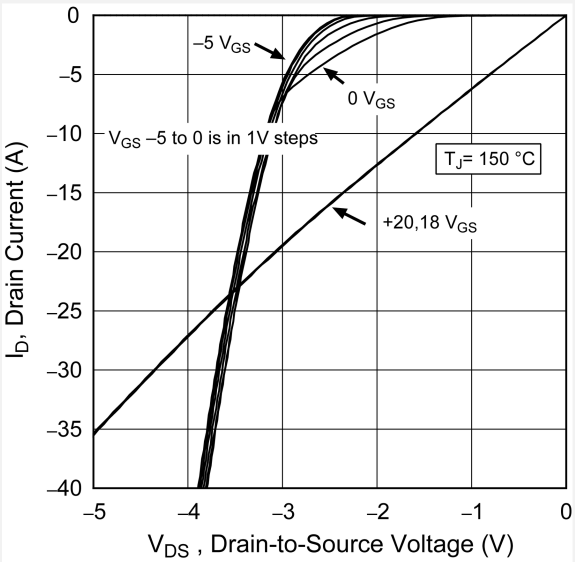


Figure 1-10. Switching Energy Eon vs. V_{DS} & I_D

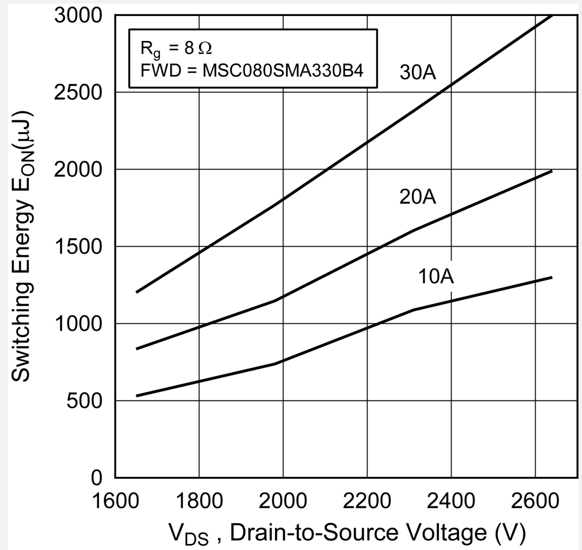


Figure 1-11. Switching Energy Eoff vs. V_{DS} & I_D

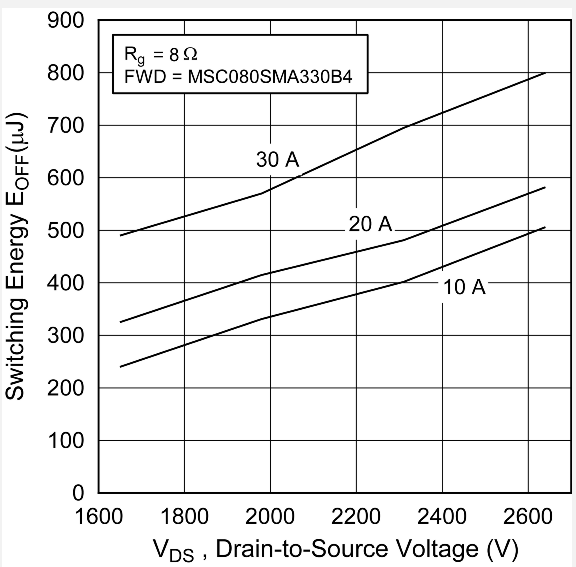


Figure 1-12. Switching Energy vs. R_g

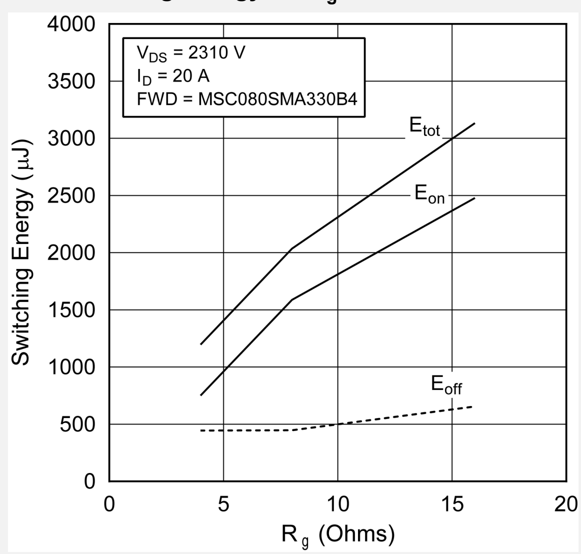


Figure 1-13. Switching Energy vs. Temperature

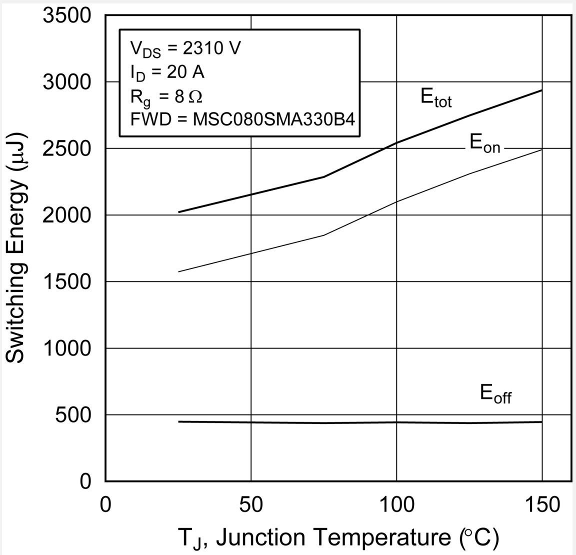


Figure 1-14. Switching Energy Eon vs. V_{DS} & I_D

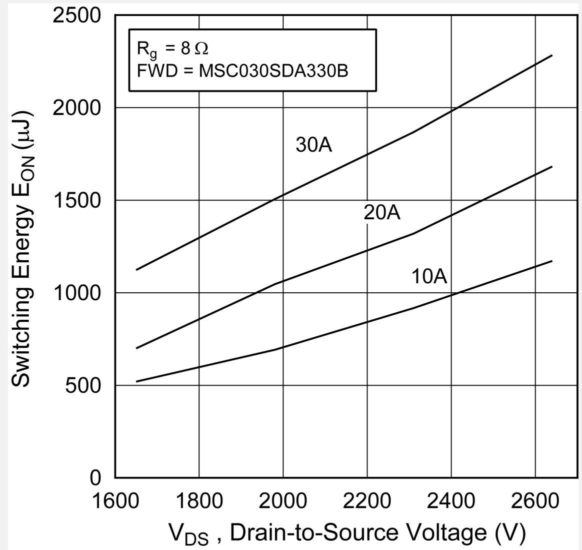


Figure 1-15. Switching Energy Eoff vs. V_{DS} & I_D

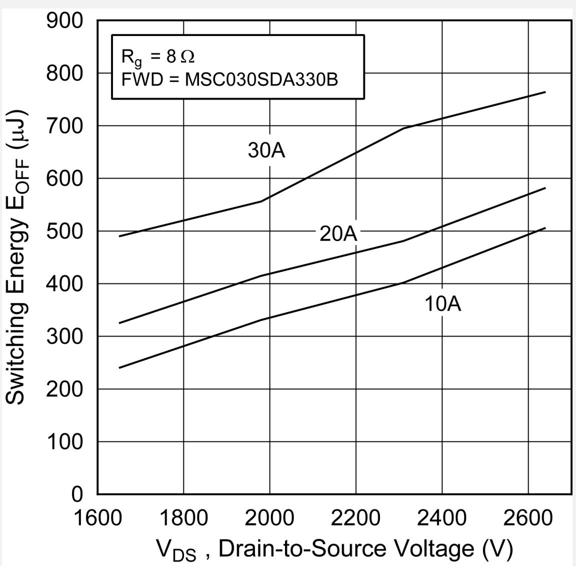


Figure 1-16. Switching Energy vs. Rg

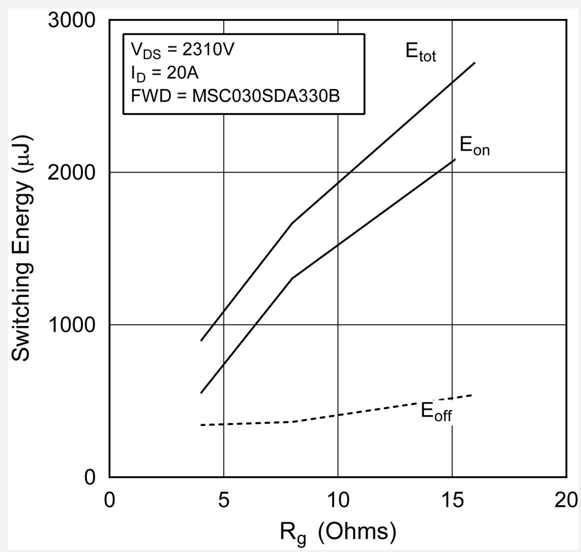


Figure 1-17. Threshold Voltage vs. Junction Temp.

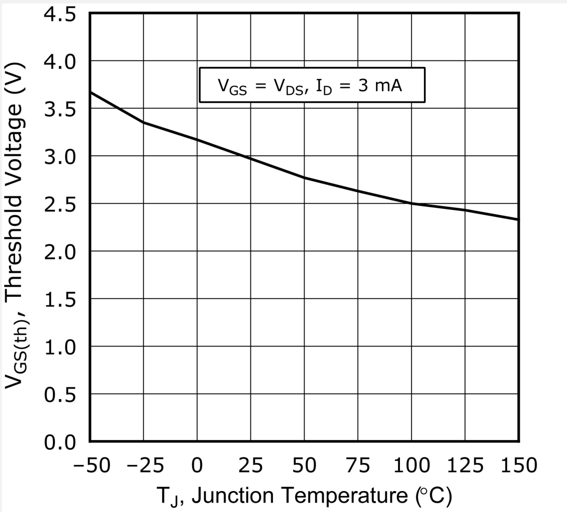


Figure 1-18. Forward Safe Operating Area

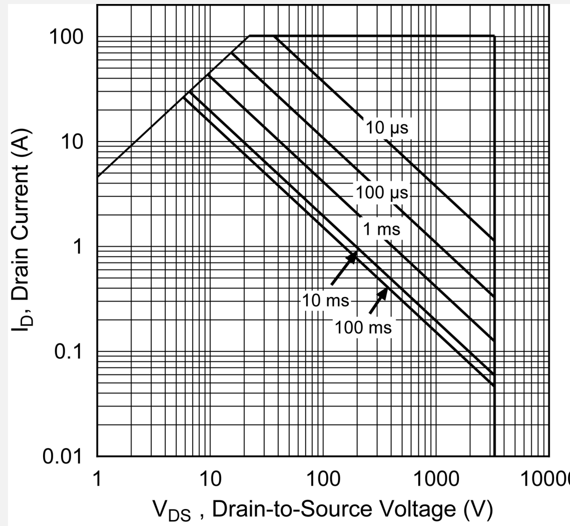
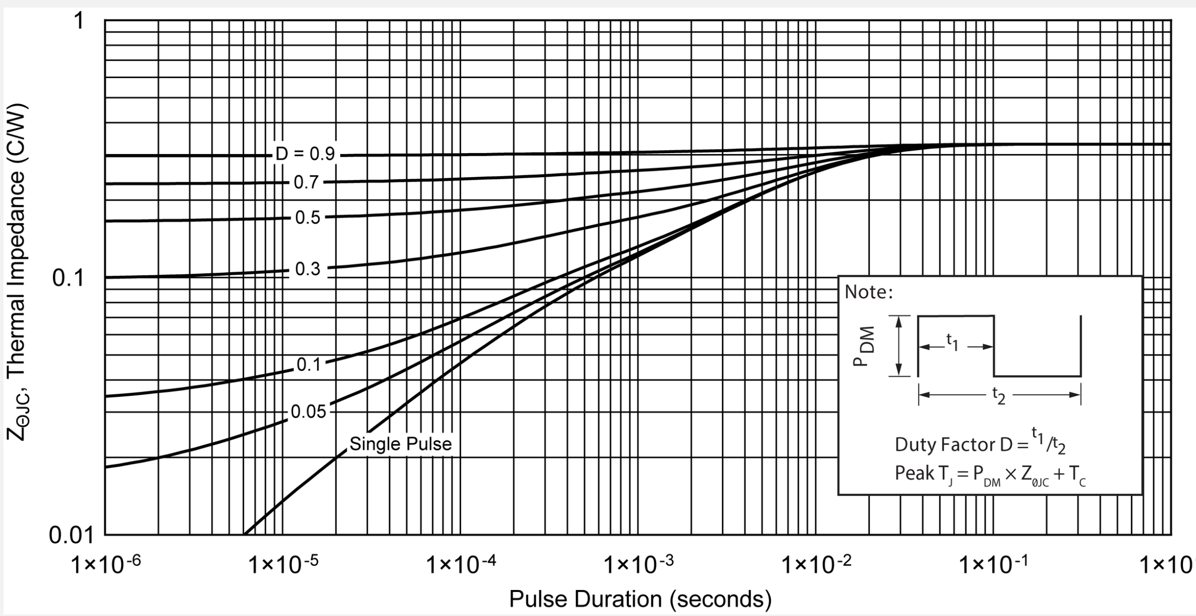
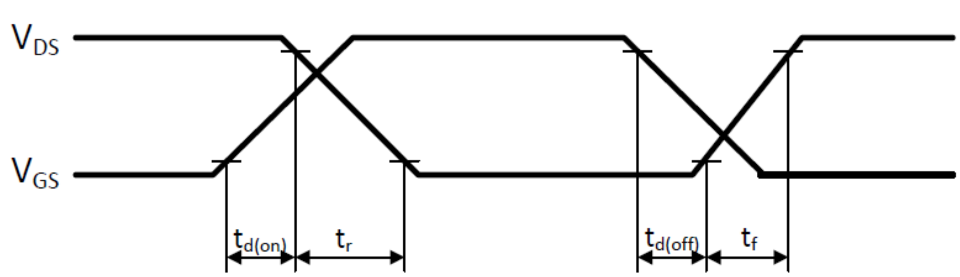


Figure 1-19. Maximum Transient Thermal Impedance



The following figure shows the switching waveform diagram of the MSC080SMA330B4 device.

Figure 1-20. Switching Waveform



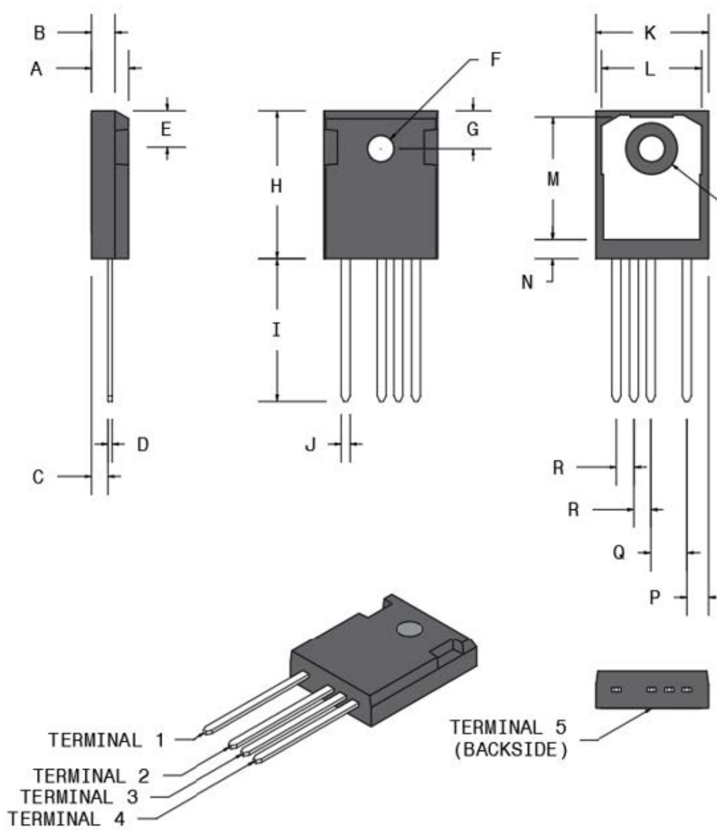
2. Package Specification

This section shows the package specification of the MSC080SMA330B4 device.

2.1 Package Outline Drawing

The following figure illustrates the TO-247-4L package outline of the MSC080SMA330B4 device.

Figure 2-1. Package Outline Drawing



The following table shows the TO-247-4L dimensions and should be used in conjunction with the package outline drawing.

Table 2-1. TO-247-4L Dimensions

Symbol	Min (mm)	Max (mm)	Min (in.)	Max (in.)
A	4.90	5.17	0.193	0.204
B	1.85	2.11	0.073	0.083
C	2.25	2.51	0.089	0.099
D	0.55	0.68	0.022	0.027
E	5.49	5.74	0.216	0.226
F	3.56	3.66	0.140	0.144
G	6.15 BSC		0.242 BSC	
H	20.83	21.08	0.820	0.830

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Symbol	Min (mm)	Max (mm)	Min (in.)	Max (in.)
I	19.81	20.32	0.780	0.800
J	1.07	1.33	0.042	0.052
K	15.77	16.03	0.621	0.631
L	13.89	14.15	0.547	0.557
M	16.25	16.85	0.640	0.663
N	2.00	2.75	0.079	0.108
O	7.10	7.50	0.280	0.295
P	2.87 BSC		0.113 BSC	
Q	5.08 BSC		0.200 BSC	
R	2.54 BSC		0.100 BSC	
Terminal 1	Drain			
Terminal 2	Source			
Terminal 3	Source sense			
Terminal 4	Gate			
Terminal 5	Drain			

3. Revision History

Table 3-1. Revision History

Revision	Date	Description
A	01/2022	Document created.

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